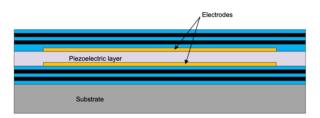
## Application Brief BAW Oscillator Solutions for Energy Infrastructure

TEXAS INSTRUMENTS

#### **BAW Resonator Technology**

BAW is a micro-resonator technology that enables the integration of high-precision and ultra-low jitter clocks directly into packages that contain other circuits. In the LMK6C and CDC6C LVCMOS oscillator families, BAW is integrated with a co-located precision temperature sensor, a ultra-low jitter, low power output divider, and a small power-reset-clock management system consisting of several low noise LDOs.

Figure 1 shows the structure of the BAW resonator technology. The structure includes a thin layer of piezoelectric film sandwiched between metal films and other layers that confine the mechanical energy. The BAW utilizes this piezoelectric transduction to generate a vibration.

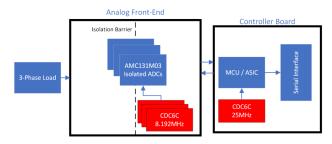


# Figure 1. Basic Structure of a Bulk Acoustic Wave (BAW) Resonator

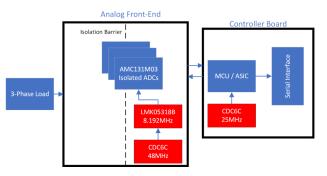
#### **BAW Oscillator in Energy Infrastructure**

The CDC6C and LMK6C LVCMOS BAW Oscillator families can be used as a drop-in replacement in energy infrastructure designs.

Figure 2 and Figure 3 demonstrate basic block diagrams a Smart Meter application in which the BAW Oscillator is incorporated. The flexibility in frequency, supply voltage, and package size allow for the BAW Oscillators to be used throughout out the entire system for alternative clocking needs. If synchronization is required for the main clocks of the isolated ADCs, a network synchronizer such as LMK05318B can be used.



#### Figure 2. Smart Meter Block Diagram with BAW Oscillator



# Figure 3. Smart Meter Block Diagram with Network Synchronizer

#### Benefits of the BAW Oscillator

One of the key benefits of the BAW oscillators in comparison to MEMs and Quartz oscillators is the exceptional jitter performance. Figure 4 shows the jitter performance of the LMK6C (LVCMOS) BAW oscillator for a 25MHz output clock. Improved jitter performance of the main clock of the ADCs can result in superior signal-to-noise ratio.

1



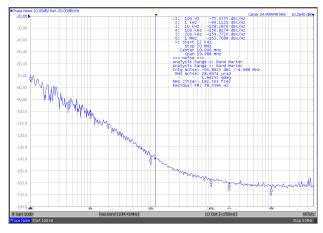


Figure 4. BAW Oscillator 25MHz Phase Noise Performance

TI's BAW Oscillator family supports 1.8V-3.3V supply voltages and are available in standard 4-pin DLE (3.2mm × 2.5mm), DLF (2.5mm × 2mm), DLX (2mm x 1.6mm), and DLY (1.6mm x 1.2mm) packages, which save space in compact board designs. Figure 5 showcases BAW Oscillator layouts on the left in comparison to typical crystal layouts for several package sizes. Crystals require up to four external components to tune the resonant frequency and maintain active oscillation. Active oscillators such as the CDC6C or LMK6C only require a single capacitor for power supply filtering, which simplifies the BOM and significantly reduces the layout area required. Additionally, parasitic capacitance from PCB traces will not affect the frequency accuracy of an active oscillator which allows it to be placed much farther away from the receiver compared to crystal.

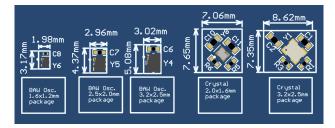


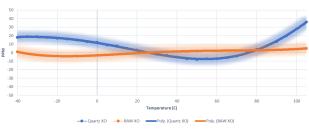
Figure 5. Layout Comparison Between Crystal and BAW Oscillators in Standard Package Sizes

BAW Oscillators offer high grade reliability in terms of temperature stability and vibration sensitivity. Figure 6 compares BAW performance to Quartz over a  $-40^{\circ}$ C to  $105^{\circ}$ C temperature range. Over temperature, the BAW oscillator has a  $\pm$  10ppm frequency accuracy.

### Trademarks

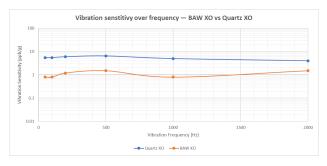
2

All trademarks are the property of their respective owners.



#### Figure 6. Temperature Stability Comparison of BAW Oscillator and Quartz Oscillator

Figure 7 shows the vibration sensitivity of the BAW oscillator. The BAW oscillator has a typical vibration sensitivity of 1ppb/g, which is significantly better than the 5-10ppb/g sensitivity of quartz oscillator designs.



#### Figure 7. Vibration Sensitivity Comparison of BAW Oscillator and Quartz

BAW oscillators have superior EMI performance compared to other technologies. Figure 8 compares the CISPR 11 radiated emissions across a 550MHz-800MHz frequency band for the CDC6C BAW oscillator and a MEMS-based oscillator. This measurement was performed using an 8.192MHz clock frequency on an AMC131M03 EVM. The BAW oscillator radiates significantly less power in the even harmonics of the clock frequency, and also emits less peak power in the odd clock harmonics.

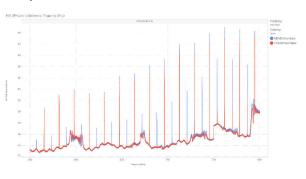


Figure 8. CISPR 11 Radiated Emissions: BAW Oscillator vs. MEMS Oscillator

### IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2024, Texas Instruments Incorporated